
1SS85

Silicon Epitaxial Planar Diode for Tuner Band Switch

HITACHI

ADE-208-152A (Z)
Rev. 1

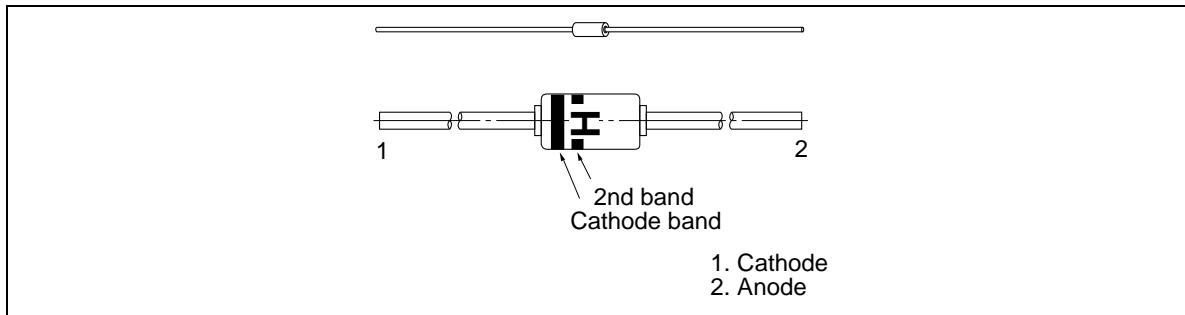
Features

- Low forward resistance. ($r_f = 0.9\Omega_{max}$)
- High reliability with glass seal.

Ordering Information

Type No.	Cathode	2nd Band	Mark	Package Code
1SS85	Verdure	Black	H	DO-35

Outline



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Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V _R	35	V
Forward current	I _F	100	mA
Junction temperature	T _j	175	°C
Storage temperature	T _{stg}	-65 to +175	°C

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	V _F	—	—	1.0	V	I _F = 10mA
Reverse voltage	V _R	35	—	—	V	I _R = 10µA
Reverse current	I _R	—	—	0.1	µA	V _R = 25V
Capacitance	C	—	—	1.2	pF	V _R = 6V, f = 1MHz
Forward resistance	r _f	—	—	0.9	Ω	I _F = 2mA, f = 100MHz

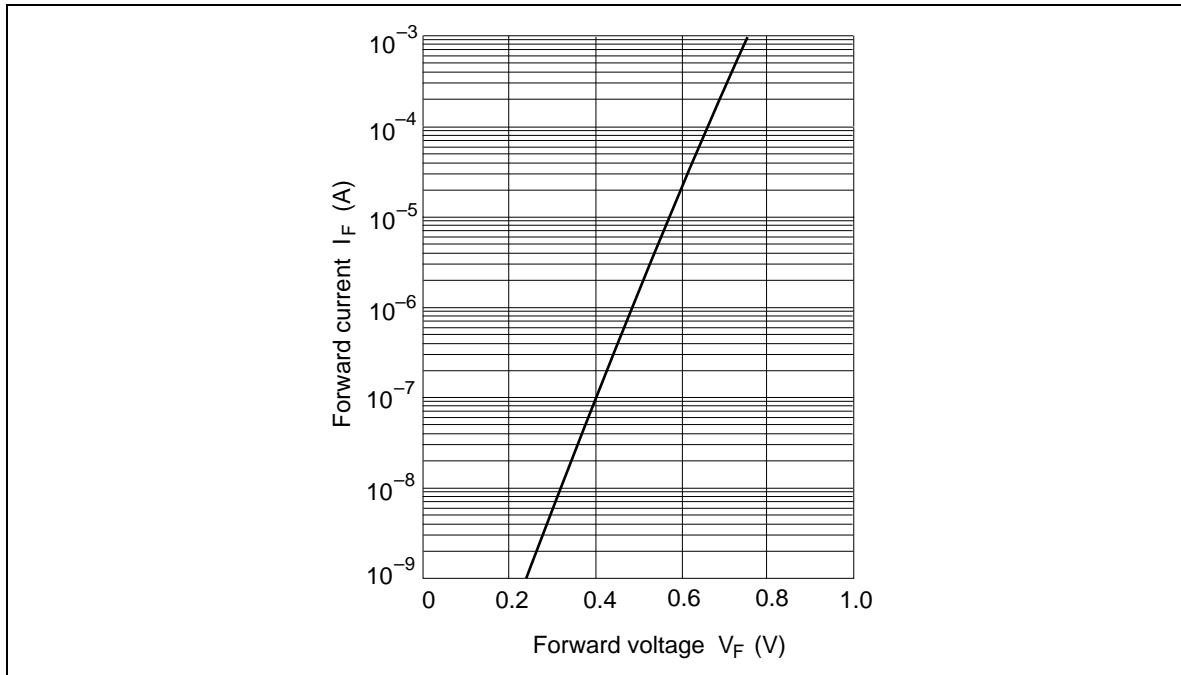


Fig.1 Forward current Vs. Forward voltage

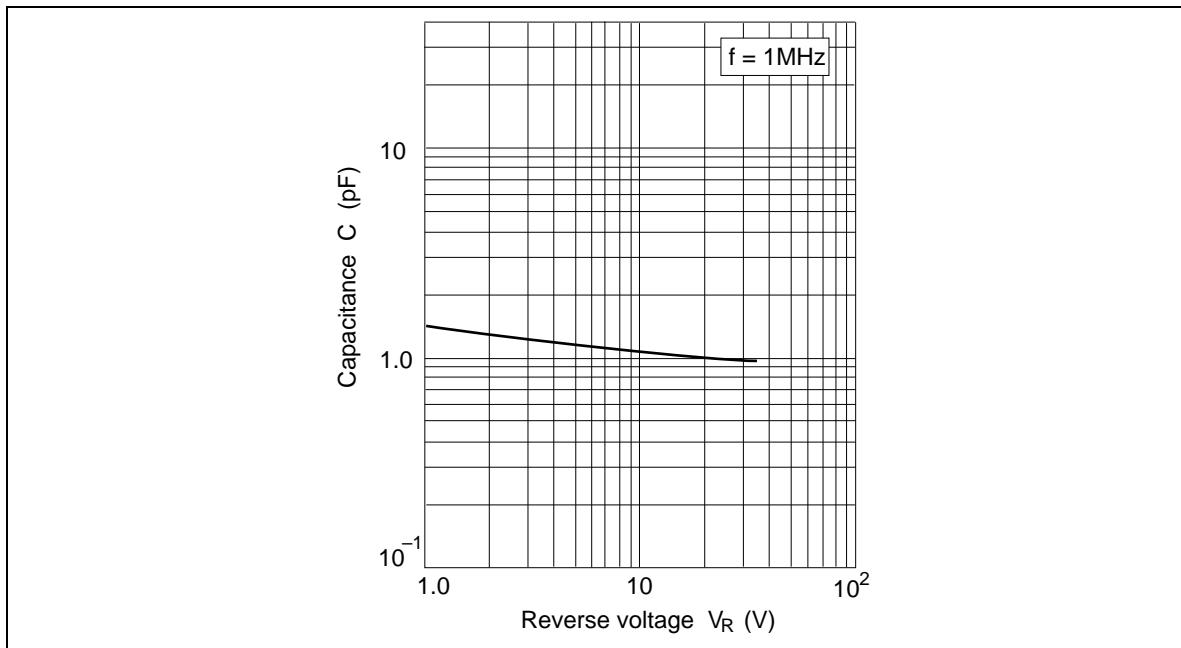


Fig.2 Capacitance Vs. Reverse voltage

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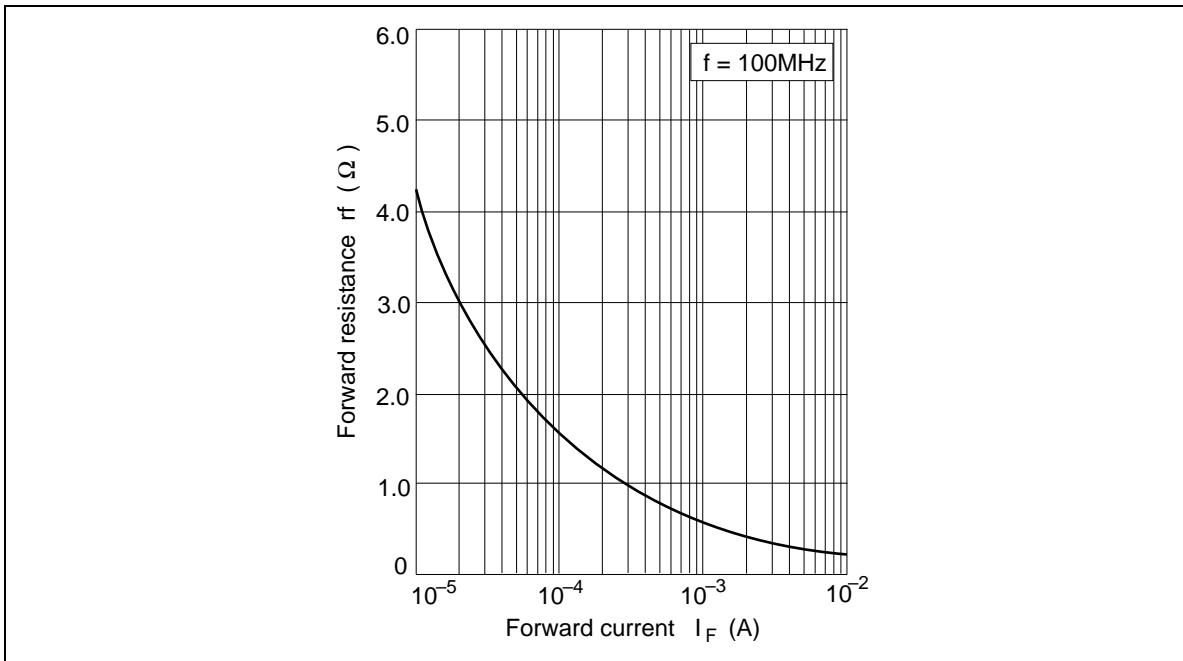


Fig.3 Forward resistance Vs. Forward current

Package Dimensions